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Josephson squelch filter for quantum nanocircuits

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We fabricated and tested a squelch circuit consisting of a copper powder filter with an embedded Josephson junction connected to ground. For small signals (squelch ON), the small junction inductance attenuates strongly from dc to at least 1 GHz, while for higher frequencies dissipation in the copper powder increases the attenuation exponentially with frequency. For large signals (squelch OFF), the circuit behaves as a regular metal powder filter. The measured ON/OFF ratio is larger than 50 dB up to 50 MHz. This squelch can be applied in low temperature measurement and control circuitry for quantum nanostructures, such as superconducting qubits and quantum dots. © 2009 American Institute of Physics. [DOI: 10.1063/1.3186047]

Quantum nanocircuits, such as superconducting qubits or semiconductor quantum dots, are nonlinear systems that are adversely influenced by noise. External noise sources are unavoidably introduced by connection lines for electrical or magnetic bias, operational signals, and measuring devices. Commonly these lines are permanently coupled to the quantum circuit. Low temperature filtering is used, but that leads to signal loss. We have developed a squelch circuit, a nonlinear filter that shorts all low amplitude signals from dc to high frequencies but transmits with low loss when a stronger signal is applied. It consists of a Josephson junction that acts as a nondissipative short for any current below its critical current, embedded in a lossy transmission line.

Filters based on lossy dielectrics using small metal grains have been extensively employed in the field of quantum nanocircuits. 1-6 Such filters consist of a metallic wire embedded in a metal powder. Via induced eddy currents in the grains, the energy of a signal propagating along the wire at higher frequencies is dissipated. Transmission starts at dc with negligible attenuation, while beyond a cutoff frequency $f_{\rm co}$ of typically 0.1 GHz the attenuation very steeply increases in a roughly exponential way with frequency. The uniform and distributed nature of these low pass filters makes them behave smoothly versus frequency, maintaining very small transmission far beyond cutoff. The Josephson junction is the element in our filter responsible for the squelch action. It has a current-voltage (I-V) characteristic which shows zero dc voltage for currents $|I_I|$ up to a critical current I_C , and acts as an inductance that for low currents is given by $L_J = \Phi_0 / 2\pi I_C$. For $|I_J| > I_C$, the voltage V shows an approximately linear increase with current. Thus, the junction can be employed as a switch, as for $|I_J| < I_C$ it has a low impedance $2\pi f L_J$, while for $|I_J| > I_C$ the effective impedance is approximately given by the Josephson junction normal state resistance, R_n .

Our squelch circuit has a Josephson junction between the signal wire and ground, mounted in the middle of a metal powder filter [Figs. 1(a) and 1(b)]. The filter properties are measured by connecting it between a source and a load, i.e., $R_0=R_L=50$ Ω [Fig. 1(d)]. In a realistic application the load is determined by the following circuit element, e.g., a super-

conducting quantum interference device attached to a flux qubit. For small signals and for frequencies $f < f_{co}$, the transmission through the filter is given by the ratio $|T| = \omega L_J / \sqrt{\omega^2 L_J^2 + R_0^2}$; with $\omega L_J \ll R_0$, we obtain $T \propto \omega$ and $T \ll 1$. For $f > f_{co}$, T is governed by the metal powder properties [see Fig. 1(e)]. For larger signals the circuit behaves as a regular metal powder filter. Note that in this regime the Josephson junction carries a nonzero voltage and so it generates Josephson oscillations at the frequency $f_J = (2e/h)V$. By mounting the junction midway of the filter, this radiation is absorbed in the metal powder since $f_J \gg f_{co}$.

Two different Josephson junctions made of aluminum have been used, with critical currents of 2.9 and 1 μ A, respectively. Taking the junction with critical current

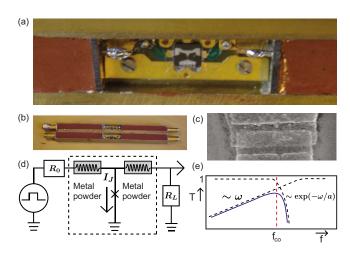


FIG. 1. (Color online) The Josephson squelch circuit. (a) Printed circuit board with the chip containing the Josephson junction. The brownish areas to the left and right is the copper loaded epoxy containing the meandering signal wires. (b) Two complete filters with SMA connectors, built side by side. The total length is 11 cm containing 80 cm of thin Cu wire. (c) Scanning electron micrograph of a Josephson junction. The junction is fabricated using electron beam lithography and double angle shadow mask evaporation. The area is $1\times0.2~\mu\text{m}^2$ and the critical current density j_C =15 $\mu\text{A}/\mu\text{m}^2$. (d) Schematic of the Josephson squelch between a source of impedance R_0 and a load R_L . The Josephson junction is represented by a cross. (e) Transmission of the Josephson squelch. For low frequencies the Josephson junction acts like an inductive short, with transmission $\sim\omega$. For frequencies higher than the cutoff frequency of the copper powder filter $f>f_{co}$, the absorption of the incoming noise increases exponentially with frequency.

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 I_C =2.9 μ A, yields L_J =110 pH and R_n =110 Ω . Experimentally we measure a copper powder filter cutoff frequency of 80 MHz (see below); for this frequency one calculates $A \approx 0.001$ or 60 dB for the small-signal attenuation by the junction inductance. The overall small-signal attenuation is smallest at 200 MHz, with $A \approx 50$ dB, shown as the maximum in Fig. 1(e). Beyond f_{co} we measure that the filter attenuation increases by approximately 65 dB/decade.

The metal powder filter is built by using a twocomponent epoxy9 loaded with copper powder. A thin (~0.1 mm) copper wire of 80 cm is meandered with a fixed spacing inside the epoxy-powder mixture so that the impedance is uniform along the filter wire. The Josephson junction is made of a 40 nm film of aluminum, fabricated using electron beam lithography and double angle shadow mask evaporation [Fig. 1(c)]. The junction sits on a 400 μ m thick thermally oxidized silicon substrate and is placed on a printed circuit board (PCB) in a gap left in the center of the copper powder filter. The PCB is attached to the housing of the copper powder filter with bolts to allow for good thermal anchoring and electrical grounding. Then it is soldered to the pins that connect to the copper wire and the chip with the Josephson junction is glued on it with silver paint and wire bonded [see Fig. 1(a)]. Finally a metallic lid is tightly screwed onto the filter housing, preventing signal leakage.

The S-parameters of the Josephson squelch were measured with a HP-8753C Network Analyzer at room temperature and at 4 K. In the transmission S_{21} the -3 dB point was seen at 80 MHz at room temperature, increasing to 100 MHz at 4 K. Beyond this frequency the transmission dropped steadily down by 50 dB at 600 MHz. The reflection S_{11} was seen to be -20 dB up to 2 GHz, corresponding to an impedance of 60 Ω .

To characterize the performance of the Josephson squelch, we mounted it on the mixing chamber of a cryogen-free dilution refrigerator with a base temperature of 15 mK. We used a cryogenic high electron mobility transistor (HEMT) amplifier on the 0.6 K still stage and a postamplifier at room temperature [Fig. 2(a)]. The post amplifier had a bandwidth of 5–50 MHz. We employed optical isolation in the input and output of a HP-4195A network spectrum analyzer together with a battery powered current source, which were combined in a bias tee at the entrance of the dilution refrigerator.

We first used the Josephson junction to probe the attenuation of the copper powder at different frequencies. We ramped a current I_{dc} through the Josephson junction to monitor its I-V characteristic [Fig. 2(b)]. For this particular junction, we observed a critical current of 2.9 μ A. On top of the ramping current, we added a high frequency signal Iac of small amplitude, $I_{\text{tot}} = I_{\text{dc}} + I_{\text{ac}}$. The ac signal reaching the junction experienced the attenuation of half the copper powder, which is frequency dependent. Signals of frequency f $\gg 2f_{\rm co}$, with $f_{\rm co} \simeq 100$ MHz being the cutoff of the copper powder filter, were strongly damped and did not affect the *I-V* characteristic [green curve in Fig. 2(b)]. As the frequency was decreased below f_{co} , the signals reaching the Josephson junction had increasing amplitude that was added to the slow current ramp, so that less $I_{\rm dc}$ was needed to reach $I_{\rm C}$. As a result, the critical current of the Josephson junction appeared to effectively decrease [as seen progressively in the brown, red, and black traces in Fig. 2(b)].

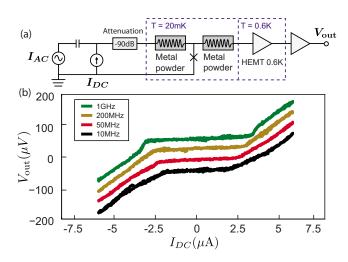


FIG. 2. (Color online) Test circuit for the Josephson squelch and characterization of the attenuation in the copper powder filter. (a) Schematic of the electrical circuit. The response of the filter is sensed by a low temperature HEMT amplifier whose output is amplified at a room temperature postamplifier. (b) Current-voltage characteristic. Different traces are vertically displaced for clarity. Each trace is taken with a 40 kHz current ramp $I_{\rm dc}$, while an ac signal $I_{\rm ac}$ at a fixed power and different frequency is added. For frequencies below the cutoff frequency of half the copper powder filter (where the junction is located) $2f_{\rm co}{=}200$ MHz the ac signal $I_{\rm ac}$ is not attenuated and less dc current $I_{\rm dc}$ is needed to reach the critical current $I_{\rm C}$.

The squelch action was probed by applying a signal of small amplitude from the network analyzer (much smaller than I_C) and then adding a dc bias $I_{\rm dc}$. In this measurement we used a Josephson junction with a critical current I_C =1 μ A. As can be seen in Fig. 3, for $I_{\rm dc} < 0.8$ μ A no signal beyond the noise floor was observed through the Josephson squelch. When the full current approached the critical current $I_{\rm dc}+I_{\rm ac}\approx I_C$, we measured a progressive increase on the voltage acquired by the amplifier. This is a direct proof of the performance of a Josephson junction used as a controllable squelch. When $I_{\rm dc} \ge 1.2$ μ A, the Josephson junction was in

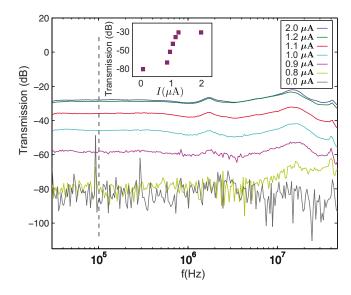


FIG. 3. (Color online) Squelch action of a Josephson junction with $I_C \approx 1~\mu A$. The transmission of the system is measured with an applied input power of $P_{\rm in}$ =-90 dBm for different values of the dc current. The topmost two traces fall together because the junction is in its dissipative state. At zero current, the transmission is the noise floor of the measurement. (Inset) Cut of the amplitude at the frequency of 100 kHz (vertical dashed line). Above 1.2 μA the dc current switches the Josephson squelch OFF. The ON/OFF ratio is 50 dB.

its dissipative state and the signal saturated. In an actual quantum circuit application [see Fig. 1(d)], when a load R_L is employed behind the Josephson squelch, the pulse that probes the load needs to have a large enough amplitude so as to switch the junction to the voltage-carrying state.

When the applied power was low enough, only the noise coming from the amplifier was observed. Taking the difference between the traces at 0 μ A and at 1.2 μ A in Fig. 3, the ON/OFF ratio was seen to be at least 50 dB up to 50 MHz, where a resonance in some part of the circuit was observed.

In summary, we have developed a squelch circuit that integrates a high frequency low-pass copper powder filter with a Josephson junction that acts as the signal-level-dependent element. The squelch operates from dc to more than 50 MHz with an ON/OFF ratio of more than 50 dB. The Josephson squelch is highly attractive for the operation of quantum nanocircuits, where the interaction between instrumentation and nanocircuit needs to be active only during specific short periods while optimal isolation is required at all other times. In particular, dephasing due to low frequency noise in control and measurement lines can be strongly suppressed.

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